# Flat Gain Amplifier

YSF-162+

## The Big Deal:

- Ultra Flat Gain Response: ± 0.2 dB over 1200-1600 MHz
- Excellent Combination of gain, P1dB, IP3 and NF
- 50Ω Input and Output: no External Components Required



## **Product Overview:**

YSF-162+ is an advanced amplifier module in a Mini-Circuits System In Package MSIP. This module is fully matched to  $50\Omega$  in/out impedance and has built-in Input & Output DC block capacitors. It is enclosed in a 5 x 6 mm MCLP plastic package. The YSF-162+ uses E-PHEMT technology enabling it to work with a single positive supply voltage.

## **Key Features**

Feature	Advantages
Superior Gain Flatness ± 0.2dB	The YSF-162+ provides industry leading gain flatness over both GPS satellite bands (1227and 1575 MHz) making this ideal for use in applications where gain-flatness and repeatability are critical performance requirements.
High Gain	The YSF-162+ is a two-stage design with internal feedback and bias to provide flat 20 dB nominal gain, supporting applications where a single gain block must overcome large system losses such as long cable runs and lossy components.
Strong Combination of Performance	The YSF-162+ provides a strong combination of performance parameters including high gain (20 dB), high IP3 (+35 dBm) and P1dB (+20 dBm) and low noise figures (2.8 dB) that are difficult to achieve in a single stage design and available only in the YSF amplifier series.
Integrated Matching, DC Blocking and Bias in Small Package	The YSF-162+ includes all support circuits including: Matching, Bias and DC Blocking, all integrated into a single 5x6mm package making the total footprint equal to or smaller than most solutions.
Excellent Return Loss	The YSF-162+ includes integrated input and output matching circuits to make this amplifier a simple, complete drop-in solution. The matching circuits provide excellent output return loss (20dB), and are designed to give optimal P1dB and IP3 performance in a $50\Omega$ environment.
High Reverse Isolation	With 30 dB of reverse isolation – the YSF-162+ is an ideal gain block for use in integrated systems to minimize VSWR interactions resulting from cascading highly reflective components such as sharp filters.



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# **Flat Gain Amplifier**

1.2-1.6 GHz

#### **Product Features**

- Matched 50-ohm surface mount amplifier
- High gain, 20 dB typ.
- Up to +20 dBm typ. output power
- High IP3, +35 dBm
- Low Noise Figure, 3.2 dB typ.
- High directivity, 31 dB isolation
- Internal Input & Output DC Block
- Separate terminal for DC

## **Typical Applications**

- GPS
- Receivers & transmitters
- Radar



CASE STYLE: DL1020 PRICE: \$2.69 ea. QTY. (20)

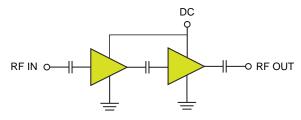
+ RoHS compliant in accordance with EU Directive (2002/95/EC)

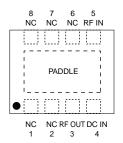
The +Suffix has been added in order to identify RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications.

## **General Description**

YSF-162+ is an advanced amplifier module in a Mini-Circuits System In Package MSIP. This module is fully matched to  $50\Omega$  in/out impedance and has built-in Input & Output DC block capacitors. It is enclosed in a 5 x 6 mm MCLP plastic package. The YSF-162+ uses E-PHEMT\* technology enabling it to work with a single positive supply voltage.

#### simplified schematic and pad description





Function	Pad Number	Description
RF-IN	5	RF Input
RF-OUT	3	RF Output
DC	4	DC Supply
GND	Paddle	Connected to ground
NOT USED	1,2,6,7,8	No internal connection

<sup>\*</sup>Enhancement mode Pseudomorphic High Electron Mobility Transistor



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ISO 9001 ISO 14001 AS 9100 CERTIFIED
P.O. Box 350166, Brooklyn, New York 11235-0003 (718) 934-4500 Fax (718) 332-4661 The Design Engineers Search Engine 2 Provides ACTUAL Data Instantly at minicipouits.com IF/RF MICROWAVE COMPONENTS

## Electrical Specifications<sup>(1)</sup> at 25°C, Zo=50Ω unless noted

Parameter	Condition (MHz)	Min.	Тур.	Max.	Units
Frequency Range		1200		1600	MHz
	1200	18.3	20.3	22.3	
Gain	1400	18.0	20.1	22.0	dB
	1600	18.0	20.0	22.0	
Gain Flatness			±0.2		dB
	1200		11.0		
Input Return Loss	1400	8.0	10.5		dB
	1600		10.0		
	1200		17.3		
Output Return Loss	1400	14.0	20.0		dB
	1600		22.0		
Reverse Isolation			31.0		dB
	1200		20.4		
Output Power @1 dB compression	1400		20.0		dBm
	1600	18.0	20.0		
Output Power @3 dB compression			21.0		dBm
	1200		36.0		
Output IP3	1400	31.0	35.0		dBm
	1600		35.0		
	1200		3.4		
Noise Figure	1400		3.2	4.2	dB
	1600		3.1		
Device Operating Voltage			5		V
Device Operating Current			118	145	mA
Device Current Variation vs. Temperature(2)			2		μΑ/°C
Device Current Variation vs Voltage			0.002		mA/mV
Thermal Resistance, junction-to-ground lead <sup>(3)</sup>			56		°C/W

<sup>(1)</sup> Measured on Mini-Circuits Characterization test board TB-589+. See Characterization Test Circuit (Fig. 1)

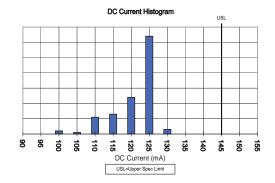
Power Dissipation

**Absolute Maximum Ratings** 

Parameter	Ratings	Units			
Operating Temperature <sup>(4)</sup>	-40 to 85	°C			
Storage Temperature	-65 to 150	°C			
DC Voltage on Pad 4	7	V			
Power Dissipation	1.5	W			
Input Power	21	dBm			

Note: Permanent damage may occur if any of these limits are exceeded.

These ratings are not intended for continuous normal operation. <sup>(4)</sup> Case is defined as ground paddle.



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<sup>(3)</sup> Thermal Resistance= Hot spot temperature - Ground lead temperature

### **Characterization Test Circuit**

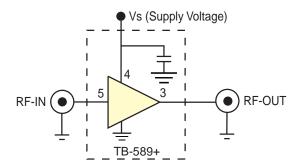


Fig 1. Block Diagram of Test Circuit used for characterization. (DUT soldered on Mini-Circuits Characterization Test Fixture TB-589+) Gain, Return loss, Output power at 1dB compression (P1 dB), Output IP3 (OIP3) and Noise Figure measured using Agilent's N5242A PNA-X microwave network analyzer.

#### Conditions:

- 1. Gain: Pin= -25dBm
- 2. Output IP3 (OIP3): Two tones, spaced 10 MHz apart, 2.5 dBm/tone at output.

## **Recommended Application Circuit**

(refer to evaluation board for PCB Layout and component values)

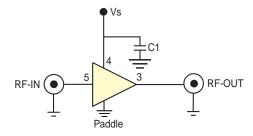
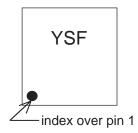


Fig 2. Recommended Application Circuit

### **Product Marking**



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Additional Detailed Technical Information (additional information is available on our web site. To access this information enter the model number on our web site home page)				
	Data Table	gol		
Performance Data	Swept Graphs	gol		
	S-Parameter (S2P Files) Data Set (.zip file)	gol		
Case Style	DL1020 Plastic package, exposed paddle, lead finish: tin/silver/nickel	gol		
Tape & Reel	F68	gol		
Suggested Layout for PCB Design	PL-335	gol		
Evaluation Board	TB-589-3+	gol		
Environmental Ratings	ENV08T1	go!		

## **ESD Rating**

Human Body Model (HBM): Class 1A in accordance with ANSI/ESD STM 5.1 - 2001

Machine Model (MM): Class M1 (25V) in accordance with ANSI/ESD STM5.2-1999

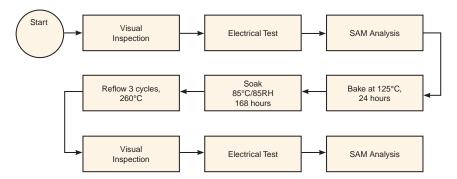


**Attention** Observe precautions for handling electrostatic sensitive devices

## **MSL** Rating

Moisture Sensitivity: MSL1 in accordance with IPC/JEDEC J-STD-020D

#### **MSL Test Flow Chart**



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